scale Semiconductor Technical Data

Low Power CMOS Photoelectric **Smoke Detector IC**

The MC146012 is an advanced smoke detector component containing sophisticated very-low power analog and digital circuitry. The IC, when used with an infrared photoelectric chamber and a small number of external components, will detect smoke by sensing scattered light from smoke particles. When detection occurs, a pulsating alarm is sounded via on-chip push-pull drivers and an external piezoelectric transducer.

The MC146012 provides both audible and visual alarms. Upon sensing a normal smoke level, both alarms will be activated. It is possible to mute the audible alarm for approximately eight minutes through the Integrated Mute Function (IMF), although the LED will continue to flash at a high rate. This feature is resetable through a pushbutton test. The IMF feature will be overridden by remote smoke, high smoke level, timeout or reset.

The Alarm memory feature will allow for identification of an alarming detector. Through a pushbutton test, the LED will flash rapidly if there was a previous alarm condition detected at the unit.

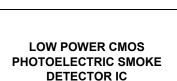
The variable-gain photo amplifier allows direct interface to IR detector (photodiode). The gain settings are determined by external capacitors and compensation resistors. A two stage speed-up is incorporated into the smoke monitor to minimize time and help reduce false triggering. Further reduction of false triggering is also addressed with the double sample chamber sensitivity and double I/O sample.

Features

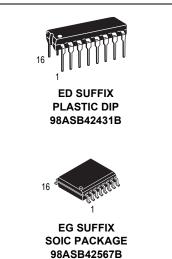
IVe

- Integrated Mute Function (IMF) to Temporarily Disable Horn
- Alarm Memory to Help Identify Alarming Unit
- Speed-Up Sampling Rate After First Detection of Smoke
- Double Sample for Degraded Chamber Sensitivity Monitor
- Digital Noise Filter on the I/O Pin
- Power-Up and Power-Down RESET
- Low-Battery Trip Point Set Externally
- **Temporal Horn Pattern**
- Operating Temperature: -10 to 75°C
- Operating Voltage Range: 6.0 to 12 V
- Average Supply Current: 6.5 µA

ORDERING INFORMATION								
Device	Temp. Range	Package						
MC146012ED	-10 to 75°C	Plastic Dip						
MCZ146012EG/R2	-1010730	SOIC Package						



MC146012





Document Number: MC146012 Rev. 1.0, 5/2007



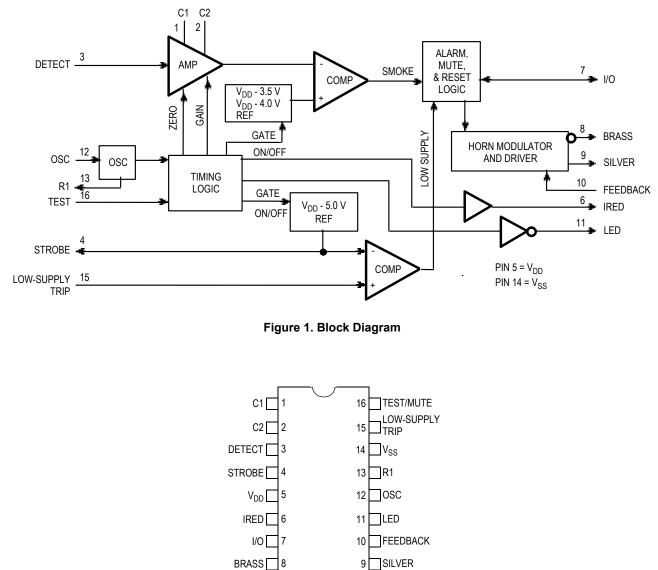


Figure 2. Pin Assignment (16-Pin DIP)

Table 1. Maximum Ratings⁽¹⁾ (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit	
V _{DD}	DC Supply Voltage		-0.5 to +12	V
V _{IN}	DC Input Voltage	C1, C2, Detect Osc, Low-Supply Trip I/O Feedback Test	$\begin{array}{c} -0.25 \text{ to } V_{DD} + 0.25 \\ -0.25 \text{ to } V_{DD} + 0.25 \\ -0.25 \text{ to } V_{DD} + 10 \\ -15 \text{ to } + 25 \\ -1.0 \text{ to } V_{DD} + 0.25 \end{array}$	V
I _{IN}	DC Input Current, per Pin		±10	mA
I _{OUT}	DC Output Current, per Pin		±25	mA
I _{DD}	DC Supply Current, V _{DD} /V _{SS} pins (15 Seconds in Reverse Dir.)		+25 Forward -150 Reverse	mA
P _D	Power Dissipation	† in Stil Air, 5 sec. †† Continuous	1200 ⁽²⁾ 350 ⁽³⁾	mW
T _{stg}	Storage Temperature		-55 to +125	°C
T _A	Operating Temperature		-25 to +75	°C
ΤL	Lead Temperature, 1 mm from case for 10 seconds		260	°C

1. Maximum ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the limits in the electrical characteristics tables.

2. Derating: -12 mW/°C from 25°C to 60°C.

3. Derating: -3.5 mW/°C from 25°C to 60°C.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of voltages any higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to a range of V_{SS} \leq (V_{IN} or

 $V_{OUT}) \leq V_{DD}$ except for I/O pin which can exceed $V_{DD},$ and the Test/Mute input, which can go below $V_{SS}.$

Unused inputs must always be tied to an appropriate logic voltage level (e.g. either V_{SS} or V_{DD}). Unused outputs and/or an unused I/O must be left open.

Symbol	Parameter	Test Condition	Test Pin	V _{DD}	Min	Мах	Unit
V_{DD}	Power Supply Voltage Range		—	—	6.0	12	V
V_{TH}	Supply Threshold Voltage, Low Supply Alarm	Low Supply Trip: $V_{IN} = V_{DD}/3$	15	—	7.2	7.8	V
I _{DD}	Average Operating Supply Current (per Package) (Does not include Current through D3-IR Emitter)	Standby Configured per Figure 5	_	12 9.0	_	9.0 7.0	μA
I _{DD}	Peak Supply Current (per Package) (Does not include IRED Current into base of Q1)	During Strobe On, IRED Off Configured per Figure 5 During Strobe On, IRED On Configured per Figure 5	_	12 12	_	1.25 2.5	mA
V _{IL}	Low Level Input Voltage I/O Feedback Test		7.0 10 16	9.0 9.0 9.0		1.5 2.7 0.5	V
V_{IM}	Mid Level Input Voltage Test		16	9.0	2.0	V _{DD} -2.0	V
V _{IH}	High Level Input Voltage I/O Feedback Test		7.0 10 16	9.0 9.0 9.0	3.2 6.3 8.5		V
I _{IN}	Input Current OSC, Detect Low-Supply Trip Feedback Test	$V_{IN} = V_{SS} \text{ or } V_{DD}$	3.12 15 10 16	12 12 12 12	-100 -100 -100 -100	+100 +100 +100 +100	nA
۱ _{IL}	Test Mode Input Current	$V_{IN} = V_{SS} \text{ or } V_{DD}$	16	12	-100	-1.0	μA

Symbol	Parameter	Test Condition	Test Pin	V_{DD}	Min	Max	Unit	
I _{IH}		est I/O	$V_{IN} = V_{DD}$ I/O $V_{IN} = V_{DD}$ I/O $V_{IN} = 17 V$	16 7.0	12 9.0 9.0 12	— 0.5 25 —	-1.0 1.0 100 140	μΑ μΑ
V _{OL}	Low-Level Output Voltage LE Silver, Bra	ED ass	I _{OUT} = 10 mA I _{OUT} = 16 mA	11 8.9	6.5 6.5	_	0.6 1.0	V
V _{OH}	High-Level Output Voltage Silver, Bra	ass	I _{OUT} = -16 mA	8.9	6.5	5.5	_	V
V _{OUT}	Output Voltage Stro (For Line Regulation, See Pin Descriptions)	be	Inactive, I _{OUT} = 1.0 μA Active, I _{OUT} = 100 to 500 μA (Load Regulation)	4.0 9.0	 9.0	V _{DD} -0.1 V _{DD} -5.4	— V _{DD} -4.6	V
I _{OH}	High-Level Output Current	I/O	Local Smoke, V _{OUT} = 4.5 V Local Smoke, V _{OUT} = V _{SS} (Short Circuit Current)	7.0 —	6.5 12	-4.0	— -16	mA
I _{OZ}	Off-State Output Leakage Current LE	ED	V_{OUT} = V_{SS} or V_{DD}	11	12	—	±100	nA
V _{OL}	Active		1.0 mA		6.5	—	0.5	V
V _{IC}	Common Mode C1, C2, Dete Voltage Range	ect	Local Smoke, Pushbutton, or Chamber Sensitivity Test	_	_	V _{DD} -4.0	V _{DD} -2.0	V
V_{REF}	Smoke Comparator Interr Reference Voltage	nal	Local Smoke, Pushbutton, or Chamber Sensitivity Test	_	_	V _{DD} -3.9	V _{DD} -3.1	V
V _{REF-HI}	High Smoke Comparator Interr Reference Voltage	nal	Local Smoke, Pushbutton, or Chamber Sensitivity Test	_	_	V _{REF} - 0.52	V _{REF} -0.48	V

* T_A = 25°C Only

Table 3. AC Electrical Characteristics (Refer to Timing Diagram Figure 3 and Figure 4. $T_A = 25^{\circ}C$, $V_{DD} = 9.0 V$, Component Values from Figure 5.)

No.	Symbol	Parameter	Test Condition	Clocks	Min ⁽¹⁾	Typ ⁽²⁾	Max ⁽¹⁾	Unit
1	1/f _{OSC}	Oscillator Period	Free-running Saw tooth Measured at Pin 12	1.0	7.2	8.0	8.8	ms
2	t _{LED}	LED Pulse Period	No Local Smoke, and No Remote Smoke	4096	28.8	32.4	35.2	S
3			Remote Smoke, but No Local Smoke	-		Extinguished	_	
4			Local Smoke	256	1.6	2.0	2.4	
5			Pushbutton Test	256	1.6	2.0	2.4	
			Push button Test with Alarm Memory	4.0	25.6	32	38.4	ms
6	t _{w(LED)} , t _{w(stb)}	LED Pulse Width and Strobe Pulse Width	Remote Smoke but No Local Smoke	1.0	OFF	—	OFF	_
7	(t _{IRED})	(I _{RED} Pulse Period)	Smoke Test	1024	7.2	8.1	8.8	s
8			Chamber Sensitivity Test, Without Local Smoke	4096	28.8	32.4	35.2	
9			Local Smoke, in Speed-Up	128	0.9	1.0	1.1	
			Pushbutton Test	128	0.9	1.0	1.1	
10	t _{w(IRED)}	IRED Pulse Width		T _f *	94	—	116	μs
11	t _R			—	-	—	30	μs
12	t _F			—	—	—	200	μs



No.	Symbol	Parameter	Test Condition	Clocks	Min ⁽¹⁾	Тур ⁽²⁾	Max ⁽¹⁾	Unit
13	t _{ON}	Silver and Brass Temporal		64	0.45	0.5	0.55	s
14	t _{OFF}	Modulation Pulse Width		64	0.45	0.5	0.55	
15	t _{OFFD}			192	1.35	1.52	1.65	
16	t _{CH}	Silver and Brass Chirp Pulse Period	Low Supply or Degraded Chamber Sensitivity	4096	28.8	32.4	35.2	s
17	t _{W(CH)}	Silver and Brass Chirp Pulse Width	Low Supply or Degraded Chamber Sensitivity	1.0	7.2	8.0	8.8	ms
18	t _{RR}	Rising Edge on I/O to Smoke Alarm Response Time	Remote Smoke, No local smoke	-	—	2.0 ⁽³⁾	_	S
19	t _{stb}	Strobe Out Pulse Period	Smoke Test	1024	7.2	8.1	8.8	s
20			Chamber Sensitivity Test Without Local Smoke	4096	28.8	32.4	35.2	S
21			Low Supply Test Without Local Smoke	4096	28.8	32.4	35.2	S
22			Pushbutton Test/Speed-Up	_	_	1.0	—	s
23	t _{MUTE}			_	6.0	8.0	11	min
Th NI 2. Ty	ne other tim FPA72, ANS picals are r	iod T (T = $T_r + T_f$) is determined by ing characteristics are some multip SI S3.41, and ISO8201 audible em not guaranteed. al-depends on what point in cycle th	ble of the oscillator timing shown i ergency evacuation signals.					

Table 3. AC Electrical Characteristics (Refer to Timing Diagram Figure 3 and Figure 4. T _A = 25°C, V _{DD} = 9.0 V,	
Component Values from Figure 5.) (continued)	



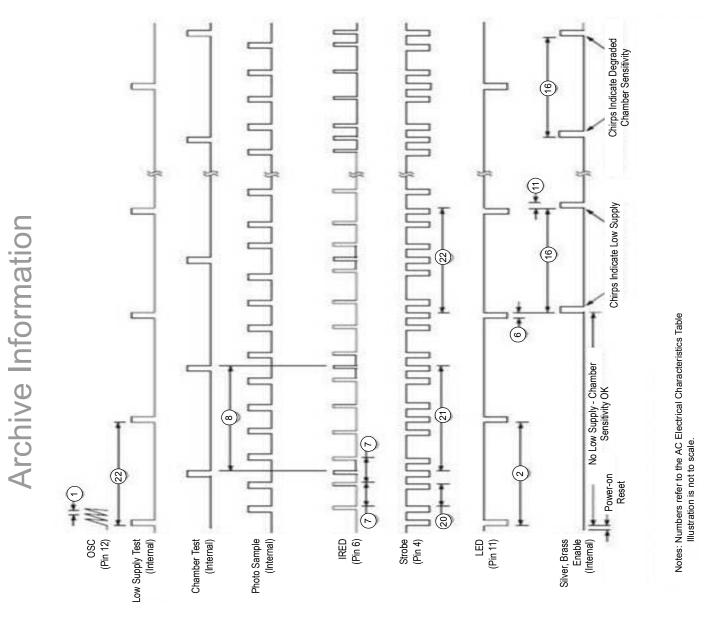


Figure 3. Typical Standby Timing Diagram MC146012 Device



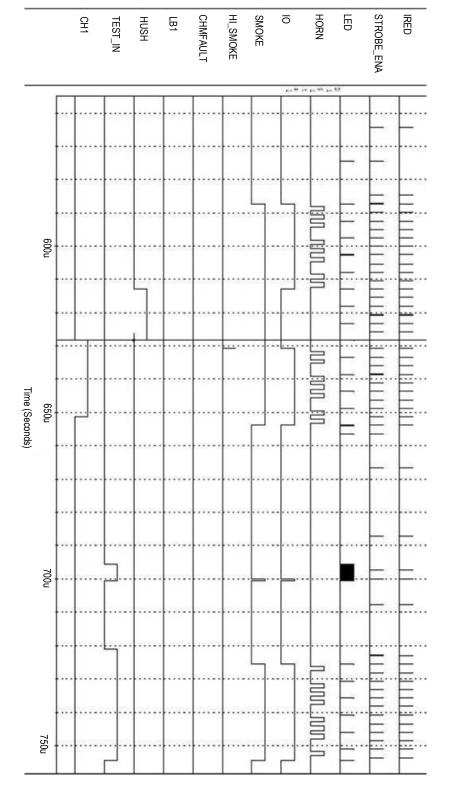


Figure 4. Typical Local Smoke Timing MC146012 Device



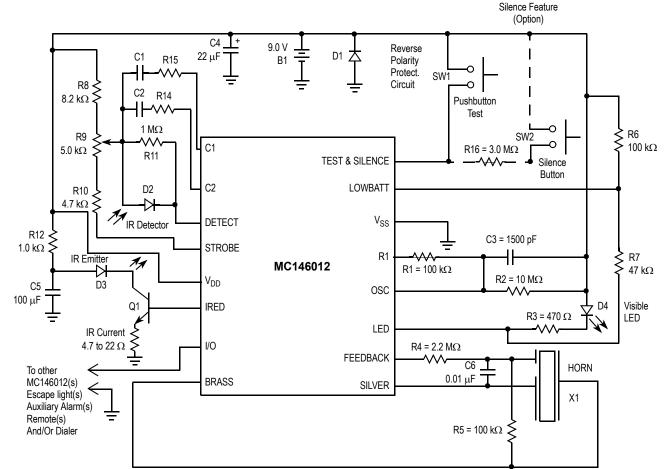


Figure 5. Typical Battery Powered Application

- # Values for R4, R5 and C6 may differ depending on type of horn used.
- * C2 and R13 are used for coarse sensitivity adjustment. Typical values are shown.
- + R9 is for fine sensitivity adjustment (optional). If fixed resistors are used, R8 = 12k, R10 is 5.6k to 10k and R9 is eliminated.
- ** Components necessary to utilize IMF feature.

PIN DESCRIPTIONS

C1 (PIN 1)

A capacitor connected to this pin as shown in Figure 5 determines the gain of the on-chip photo amplifier during pushbutton test and chamber sensitivity test (high gain). The capacitor value is chosen such that the alarm tripped from background reflections in the chamber during pushbutton test.

AV = 1+(C1/10) where C1 is in pF. CAUTION: The value of the closed-loop gain should not exceed 10,000.

Resistor R15 should be installed in series with C1 for lower gains. R15 =[$1/(12\sqrt{C1})$ -680 where R15 is in ohms and C1 is in farads.

C2 (PIN 2)

A capacitor connected to this pin as shown in Figure 5 determines the gain of the on-chip photo amplifier during pushbutton test and chamber sensitivity tests.

AV = 1+(C2/10) where C1 is in pF. This gain increases about 10% during IRED pulse, after two consecutive local smoke detections.

For proper compensation, resistor R14 must be installed in series with C2. R14 =[$1/(12\sqrt{C2})$ -680 where R14 is in ohms and C1 is in farads.

DETECT (PIN 3)

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This input to the high-gain pulse amplifier is tied to the cathode of an external photodiode. The photodiode should have low capacitance and low dark leakage current. The diode must be shunted by a load resistor and is operated at zero bias.

The Detect input must be ac/dc decoupled from all other signals, V_{DD} and V_{SS} . Lead length and/or foil traces to this pin must be minimized also. See Figure 3.

The device has a sampling speed-up mode after the first smoke sample is detected. The speed-up frequency is one smoke sample about every 2 seconds for the duration of a smoke condition. It will take no-smoke samples to return to a standby mode. Once out of a smoke condition, the IC will continue to sample for smoke about every 8 seconds.

STROBE (PIN 4)

This output provides the strobed, regulated voltage referenced to V_{DD}. The temperature coefficient of this voltage is $\pm 0.2\%$ /°C maximum from -10 to 60°C. The supply-voltage coefficient (line regulation) is $\pm 0.2\%$ /V maximum from 6.0 to 12 V. Strobe is tied to external resistor string R8, R9 and R10.

V_{DD} (PIN 5)

This pin is connected to the positive supply potential and may range from +6.0 to +12 V with respect to $V_{SS}.$

CAUTION: In battery-powered applications, reversepolarity protection must be provided externally.

IRED (PIN 6)

This output provides pulsed base current for external NPN transistor Q1 used as the infrared emitter driver. Q1 must have a $\beta \ge 100$. At 10 mA, the temperature coefficient of the

output voltage is typically +0.5%/°C from -10 to 60°C. The supply-voltage coefficient (line regulation) is $\pm 0.2\%/V$ maximum from 6.0 to 12 V. The IRED pulse width (active-high) is determined by external components R1 and C3. With a 100 k Ω /1500 pF combination, the nominal width is 105 µs.

To minimize noise impact, IRED is active near the end of strobe pulses for smoke tests, chamber sensitivity test, and pushbutton test. For the above mentioned width, IRED will be active for the last 105 μ s of strobe pulse.

I/O (PIN 7)

This pin can be used to connect up to 40 units together in a wired-OR configuration for common signaling. V_{SS} is used as the return. An on-chip current sink minimizes noise pickup during non-smoke conditions and eliminates the need for an external pull-down resistor to complete the wired-OR. Remote units at lower supply voltages do not draw excessive current from a sending unit at higher supply voltage.

I/O can also be used to activate escape lights, auxiliary alarms, remote alarms and/or auto-dialers.

As an input, this pin feeds a positive-edge-triggered flipflop whose output is sampled nominally every 1 second during standby (using typical component values). Once the first I/O remote smoke sample is detected, a second sample approximately 10 ms later will happen to confirm a remote smoke condition. If both samples are found to be high, the unit will start sounding an alarm.

I/O is disabled by the on-chip power-on reset to eliminate nuisance signaling during battery changes or system power-up.

If unused, I/O must be left unconnected.

BRASS (PIN 8)

This half of the push-pull driver output is connected to the metal support electrode of the piezoelectric audio transducer and to the horn-starting resistor. A continuous modulated tone from the transducer is a smoke alarm indicating either local or remote smoke. A short beep or chirp is a trouble alarm indicating a low supply or degraded chamber sensitivity. A series of short beeps or chirps during a pushbutton test indicate a previous alarm for detected smoke (Alarm memory feature).

SILVER (PIN 9)

This half of the push-pull driver output is connected to the ceramic electrode of a piezoelectric transducer and to the horn-starting capacitor.

FEEDBACK (PIN 10)

This input is connected to both the feedback electrode of a self-resonating piezoelectric transducer and the horn-starting resistor and capacitor through current limiting resistor R4. If unused, the pin must be tied to V_{SS} or V_{DD} .

LED (PIN11)

This active-low open drain output directly drives an external visible LED at the pulse rate indicated below. The pulse width is equal to the OSC period.



The load for the low-supply test is non-coincident with the smoke tests, chamber sensitivity test, pushbutton test, or any alarm signals.

The LED also provides a visual indication of the detector status as follows, assuming the component values shown in Figure 4:

Standby (includes low-supply and chamber sensitivity tests) — Pulses every 32.4 seconds.

Local Smoke — Pulses every 2.0 seconds (typical) Mute — Pulses every 2.0 seconds (typical) Remote Smoke — No Pulses Pushbutton test — Pulses every 2.0 seconds

OSC (PIN 12)

This pin is used in conjunction with external resistor R2 (7.5 M Ω) to V_{DD} and external capacitor C3 (1500 pF) to V_{DD} to form an oscillator with a nominal period of 7.9 msec (typical).

R1 (PIN 13)

This pin is use din conjunction with resistor R1(100 k Ω) to pin 12 and C3 (1500 pF, see pin 12 description) to determine the IRED pulse width. With this RC combination, the nominal pulse width is 105 μ s.

V_{SS} (PIN 14)

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This pin is the negative supply potential and the return for the I/O pin. Pin 14 is usually tied to Ground.

LOW-SUPPLY TRIP (PIN 15)

This pin is connected to an external voltage which determines the low-supply alarm threshold. The trip voltage is obtained through a resistor divider connected between the V_{DD} and LED pins. The low-supply alarm threshold voltage (in volts) = (5R7/R6)+5 where R6 and R7 are in the same units.

TEST/MUTE (PIN 16)

This input has an on-chip pull-down device and is used to manually invoke a test mode, a mute mode, or a calibration mode.

The *Pushbutton Test* mode is initiated by a high level at Pin 16 (usually a depression of a S.P.S.T. normally-open pushbutton switch to V_{DD}). After one oscillator cycle, the IRED pulses approximately every 1.0 second, regardless of the presence of smoke. Additionally, the amplifier gain is increased by automatic selection of C1. Therefore the background reflections in the smoke chamber may be interpreted as smoke, generating a simulated smoke condition. After the second IRED pulse, a successful test activates the horn-driver and I/O circuits. The active I/O allows remote signaling for a system testing. When the Pushbutton Test switch is released, the Test input returns to V_{SS} due to the on-chip pull-down device. After one oscillator cycle, the amplifier gain returns to normal, thereby removing the simulated smoke condition. After two additional IRED pulses, less than three seconds, the IC exits the alarm mode and returns to standby timing.

The Pushbutton Test will also activate the Alarm Memory feature. If there was a previous alarm detected by the unit, the horn will chirp every 1/4 second as long as the Test Button is pressed. Upon releasing of the Test Button, Alarm memory will be reset. Subsequent pressing of the Test Button will result in a Pushbutton Test for simulated smoke.

Pressing the Test Button while in the MUTE mode will result in resetting of MUTE (and additionally a normal Pushbutton Test).

The MUTE mode (IMF) is initiated by a mid level voltage (around $\frac{1}{2}$ V_{DD}) at pin 16. A parallel Mute Button to an existing Test Button needs to be installed at the test pin. A smoke condition must be present for the MUTE mode to be activated. If a no smoke condition gets detected while in the MUTE mode, the IMF 8 minute window gets reset. The unit will return to Standby mode.

Once in the MUTE mode, the audible smoke alarm (horn) is temporarily disabled for approximately 8 minutes while smoke condition is being detected. A visual smoke alarm will remain (LED flashing) during MUTE mode. A high smoke voltage reference will also be activated at this time. Simultaneous smoke and high smoke sampling will allow the unit to enable the horn driver in case a high smoke condition occurs during MUTE where the high smoke threshold is crossed.

The MUTE mode can be overridden by the following conditions: 1) a no smoke condition is detected, 2) high smoke level detected, 3) remote smoke detected through I/O, 4) reset through test Button, 5) timeout of 8 minute window. To help prevent a jammed Mute Button condition, the divider string on the Mute Button should include a resistor to V_{DD} , R15 (around 10 M Ω) and a resistor R16 (4.7 M Ω) and capacitor, C7 (0.047 mF) in series to V_{SS} .

CALIBRATION

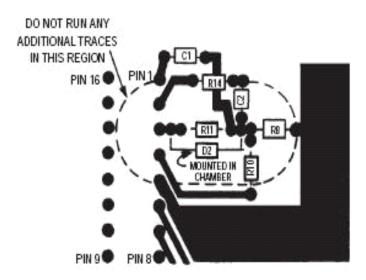
To facilitate checking the sensitivity and calibrating smoke detectors, the MC146012 can be placed in Calibration mode. In this mode, certain device pins are controlled/reconfigured as shown in Table 4. To place the part in Calibration mode, Pin 16 (Test/ Mute) must be pulled below V_{SS} pin with 100 μ A continuously drawn out of the pin for at least one cycle of the OSC pin. To exit this mode, the Test/ Mute pin is floated for at least one OSC cycle.

In the Calibration mode, the IRED pulse rate is increased. An IRED pulse occurs every clock cycle. Also, Strobe is always Active Low. It is recommended to short R12 (Figure 5) in this mode. This will allow for a similar recovery of the emitter circuitry as in normal operation. Pin 1, pin 2, and pin 12 should be buffered with a unity gain amplifier to measure their outputs.



Table 4. MC146012 Test Mode Logic Table

Pin	Function	Туре	Logic	Description
Pin 16, TEST	Test Mode 1 Trigger	Input	None	Set a –Ve voltage to the pin and source 100 μA from the pin to start Test Mode 1.
Pin 12, OSC CAP	Clock Input	Input	0	Internal clock low
			1	Internal clock high
Pin 5, V _{DD}	Chip Power			
Pin 14, V _{SS}	Chip Ground			
Pin 11, LED	Built-in-Test for HUSH Timer	Output		Output pulse active low for 8 Clocks every 128 Clocks.
Pin 4, STROBE	Analog Ground	Output		Output low when pin 12 is low.
Pin 6, IRED	IRED	Output	0	Output low when pin 12 is low.
			1	Output high (3.0 V) when pin 12 is high.
Pin 3, DETECT	Smoke Sensing Input	Input		NO SMK: V _{DD} -2.5 V – (1/Hi Gain)
				SMK: V _{DD} -2.5 V –(1/Low Gain)
				HI SMK: V _{DD} -2.5 V – (2/Low Gain)
Pin 8, BRASS	Smoke Latch Indicator	Output	0	Output low when smoke latch not set.
			1	Output high when smoke latch set.
Pin 9, SILVER	Photo-Comparator Indicator	Output	0	Output low when photo comparator not set.
			1	Output high when photo comparator set.
Pin 7, I/O	Photo-Amp Routing Enable	Input	0	Disable the function of Pin 1, 2, 10 and 15 in Test Mode 1.
			1	Enable photoamplifier output routed to the pins and enable pins 1, 2, 10 and 15 in test Mode 1.
Pin 15, LOW_BATT	Low Battery Trip Point	Input		Control photo amp. Gain and output routing
Pin 10, FEEDBACK	Feedback	Input		Control hysteresis



NOTES: Illustration is bottom view of layout using a DIP. Top view for SOIC layout is mirror image.

Optional potentiometer R9 is not included.

Drawing is not to scale.

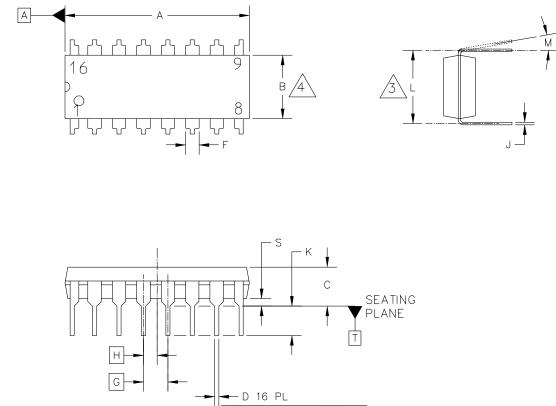
Leads on D2, R11, R8, and R10 and their associated traces must be kept as short as possible. This practice minimizes noise pick up.

Pin 3 must be decoupled from all other traces.

Figure 6. Recommended PCB layout



PACKAGE DIMENSIONS



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		CASE NUMBER	CASE NUMBER: 648-08			
		STANDARD: NE	IN-JEDEC			

98ASB42431B ISSUE T PLASTIC DIP PAGE 1 OF 3

98ASB42431B **ISSUE T** PLASTIC DIP

PAGE 2 OF 3

	MILLIN	IETERS	11	NCHES		MILI	lMeters		INCHES
DIM	MIN	MAX	MIN	MAX	DIM	MIN	MAX	MIN	MAX
А	18.80	19.55	0.740	0.770					
В	6.35	6.85	0.250	0.270					
С	3.69	4.44	0.145	0.175					
D	0.39	0.53	0.015	0.021					
F	1.02	1.77	0.040	0.070					
G	2.54	BSC	0.1	00 BSC					
Н	1.27	BSC	0.0	50 BSC					
J	0.21	0.38	0.008	0.015					
К	2.80	3.30	0.110	0.130					
L	7.50	7.74	0.295	0.305					
М	0.	10.	0.	10.					
S	0.51	1.01	0.020	0.040					
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Archive Information

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NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: INCH.
- A DIMENSION TO CENTER OF LEADS WHEN FORMED PARALLEL.
- A. DIMENSIONS DOES NOT INCLUDE MOLD FLASH.
- 5. ROUNDED CORNERS OPTIONAL.
- 6. 648-01 THRU -08 OBSOLETE, NEW STANDARD 648-09.



PACKAGE DIMENSIONS

STYLE 1:	STYLE 2:
PIN 1. CATHODE	PIN 1. COMMON DRAIN
2. CATHODE	2. COMMON DRAIN
3. CATHODE	3. COMMON DRAIN
4. CATHODE	4. COMMON DRAIN
5. CATHODE	5. COMMON DRAIN
6. CATHODE	6. COMMON DRAIN
7. CATHODE	7. COMMON DRAIN
8. CATHODE	8. COMMON DRAIN
9. ANODE	9. GATE
10. ANODE	10. SOURCE
11. ANODE	11. GATE
12. ANODE	12. SOURCE
13. ANODE	13. GATE
14. ANODE	14. SOURCE
15. ANODE	15. GATE
16. ANODE	16. SOURCE

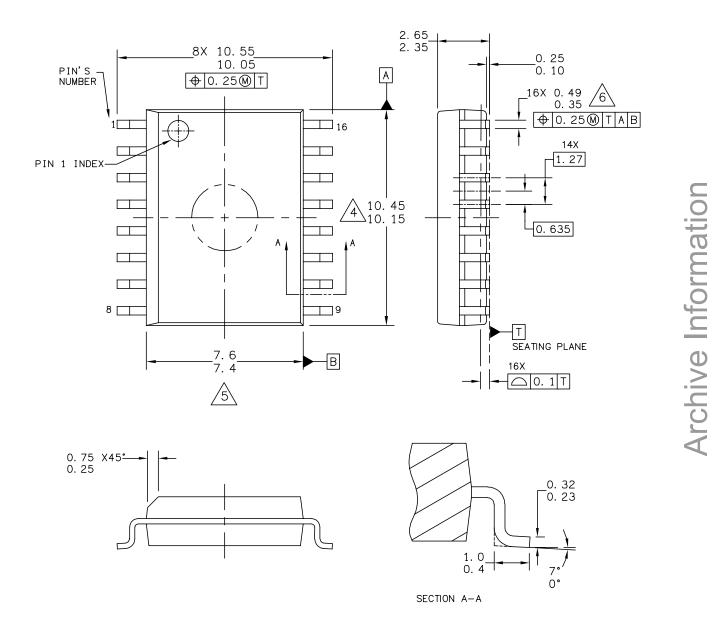
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TITLE:		DOCUMENT NO): 98ASB42431B	REV: T
16 LD PDIP		CASE NUMBER	₹: 648–08	19 MAY 2005
		STANDARD: NON-JEDEC		

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98ASB42431B ISSUE T PLASTIC DIP



PACKAGE DIMENSIONS



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		CASE NUMBER	R: 751G-04	02 JUN 2005
		STANDARD: JEDEC MS-013AA		

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98ASB42567B ISSUE F SOIC PACKAGE



PACKAGE DIMENSIONS

NOTES:

- 1. DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 3. DATUMS A AND B TO BE DETERMINED AT THE PLANE WHERE THE BOTTOM OF THE LEADS EXIT THE PLASTIC BODY.
- THIS DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURRS. MOLD FLASH, PROTRUSION OR GATE BURRS SHALL NOT EXCEED 0.15 MM PER SIDE. THIS DIMENSION IS DETERMINED AT THE PLANE WHERE THE BOTTOM OF THE LEADS EXIT THE PLASTIC BODY.
- THIS DIMENSION DOES NOT INCLUDE INTER-LEAD FLASH OR PROTRUSIONS. INTER-LEAD FLASH AND PROTRUSIONS SHALL NOT EXCEED 0.25 MM PER SIDE. THIS DIMENSION IS DETERMINED AT THE PLANE WHERE THE BOTTOM OF THE LEADS EXIT THE PLASTIC BODY.
- THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED 0.62 mm.

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16LD SOIC W/B, 1.27 PITCH CASE OUTLINE	CASE NUMBER	R: 751G-04	02 JUN 2005
CASE OUTLINE	STANDARD: JEDEC MS-013AA		

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